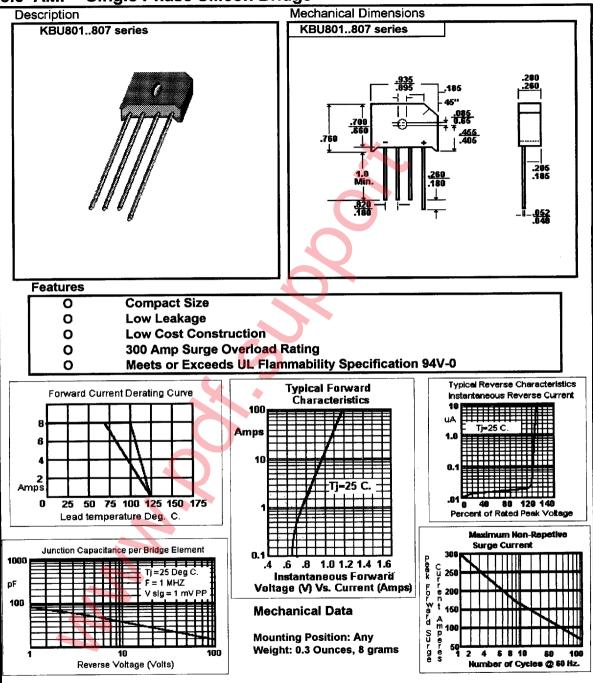
8.0 AMP Single Phase Silicon Bridge



FCI Semiconductor 350 Town & Country Village. San Jose, CA 95128 TEL (408) 985 4571 FAX (408) 261 8289

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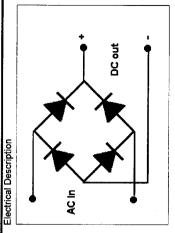
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Single Phase Silicon Bridge Semiconductor 8.0 AMP

KBU801807 series	KBU803 KBU804 KBU805 KBU806 KBU807 200 400 600 800 1000 140 280 420 560 700 200 400 600 800 1000	KBU801 KBU802 50 100 35 70 50 100	Voltage. Tc=100 Deg. C ated load 1 DC 5 C.
KBU801 50 35 35 50 00 Deg. C	10		Bridge Element of 4.0 Amp Maximum Reverse Current, @ Rated DC TA=25 C. TA=100 C.
ridge Input Voltage. 50 ridge Input Voltage. 35 cking Voltage. 50 e Forward Current Tc=100 Deg. C	300		Surge Current
KBU801 KBU802 KBU803 KBU804 KBU805 KBU806 KBU806<			rage Forward Current Tc=100 Deg. C
rse Voltage. 50 35	400 600 800	100	Blocking Voltage.
KBU801	280 420 560	<u>8</u> 8	S Bridge Input Voltage.
	KBU803 KBU804 KBU805 KBU806 KBU807		Control Day Day of Control

8.0 AMP Single Phase Silicon Bridge **KBU801..807 series**

Ratings at 25 Deg. C. ambient temperature unless otherwise specified. Single Phase Half Wave, 60 HZ Resistive or Inductive Load. For Capacitive Load, Derate current by 20%.



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